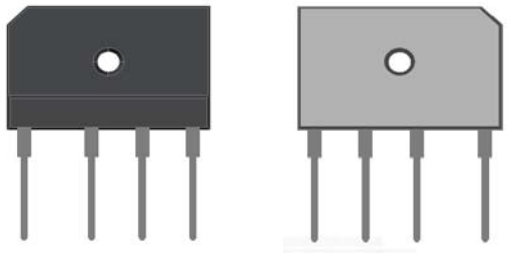
Bridge Rectifiers



Features

- Glass passivated chip junction
- Thin single in-line package
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Mechanical Data

- **Package**: PB
  Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■Maximum Ratings (Ta=25℃ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	YG50DD60	YG50DD80	YG50DD100	YG50DD120
Device marking code				YG50DD60	YG50DD80	YG50DD100	YG50DD120
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	V	600	800	1000	1200
Maximum RMS Voltage		V_{RMS}	V	420	560	700	840
Maximum DC blocking Voltage		V_{DC}	V	600	800	1000	1200
Average rectified output current @60Hz sine wave, R-load	With heatsink Tc =100℃	I_O	A	50*2			
	Without heatsink Ta =25℃			15*2			
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25℃		I_{FSM}	A	600			
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25℃				1200			
Current squared time @1ms≤t≤8.3ms Tj=25℃, Rating of per diode		I^2t	A^2s	1490			
Storage temperature		T_{stg}	℃	-55 ~ +150			
Junction temperature		T_j	℃	-55 ~ +150			
Dielectric strength @ Terminals to case, AC 1 minute		V_{dis}	KV	2.5			
Mounting torque @Recommend torque：5kg·cm		Tor	kg·cm	8			

■Electrical Characteristics（Ta=25℃ Unless otherwise specified）

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	YG50DD60	YG50DD80	YG50DD100	YG50DD120
Maximum instantaneous forward voltage drop per diode	V_F	V	I_{FM}=25.0A	1.05			
Maximum DC reverse current at rated DC blocking voltage per diode	I_R	μA	T_j=25℃	5			
			T_j=125℃	500			
Typical junction capacitance	Cj	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	292			

■Thermal Characteristics （T_a=25℃ Unless otherwise specified）

PARAMETER		SYMBOL	UNIT	YG50DD60	YG50DD80	YG50DD100	YG50DD120
Thermal Resistance	Between junction and ambient, Without heatsink	$R_{\theta J-A}$	℃/W	18.0			
	Between junction and case, With heatsink	$R_{\theta J-C}$		0.75			

Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

■Ordering Information (Example)

PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YG50DD60 THRU YG50DD120	B1	Approximate 7.5	15	750	1500	TUBE

■ Characteristics (Typical)

FIG1:Io-Tc Curve

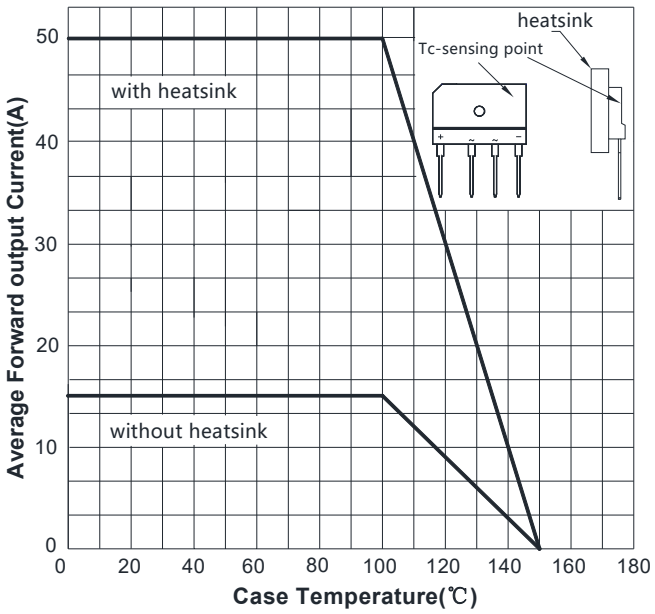


FIG2:Surge Forward Current Capability

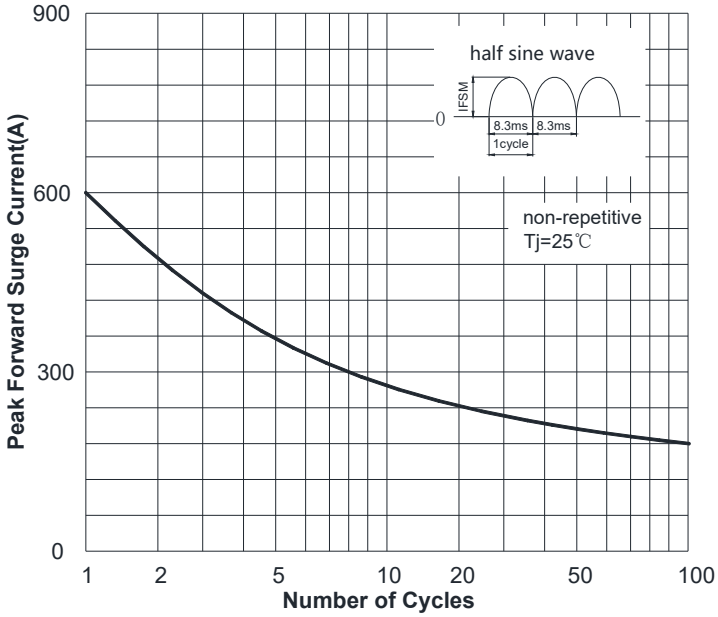


FIG3: Typical Forward Voltage

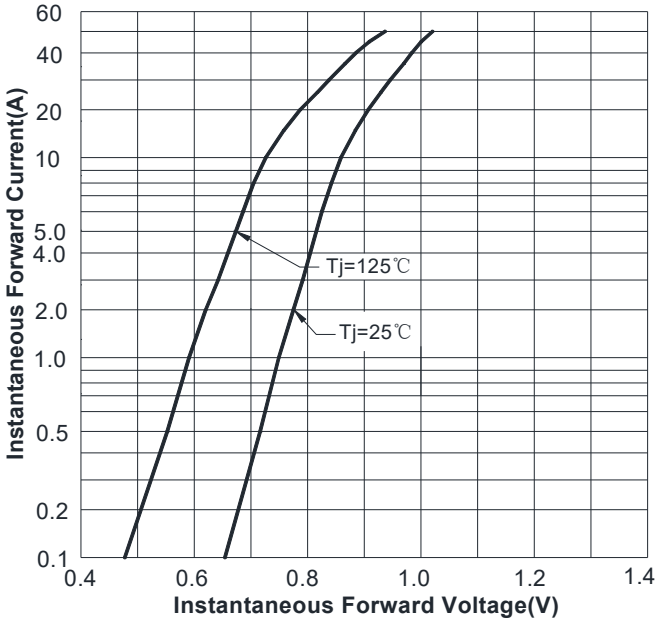
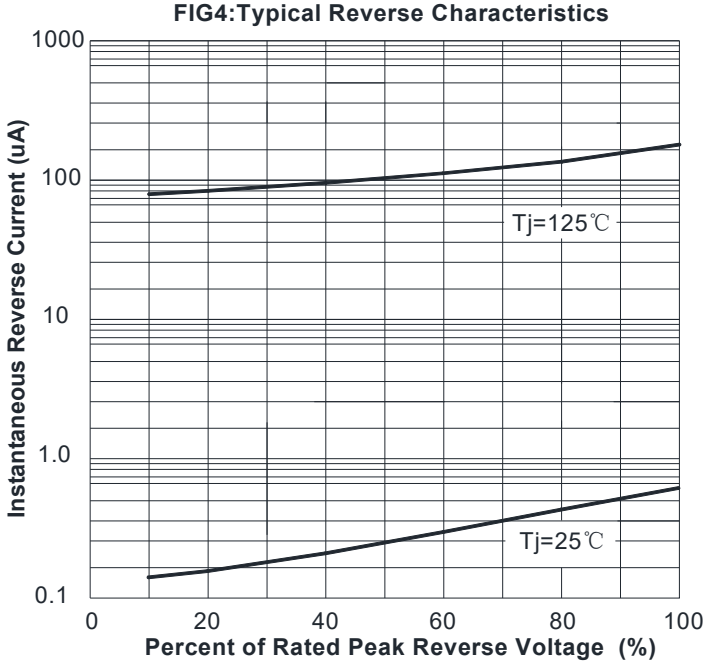
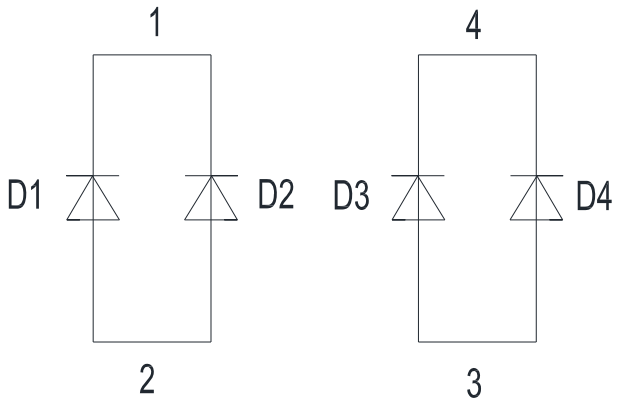


FIG4:Typical Reverse Characteristics

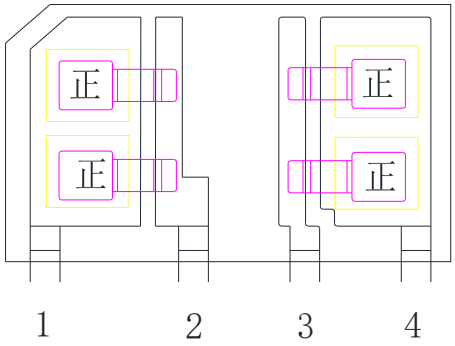


■ Electrical circuit diagram and structural diagram

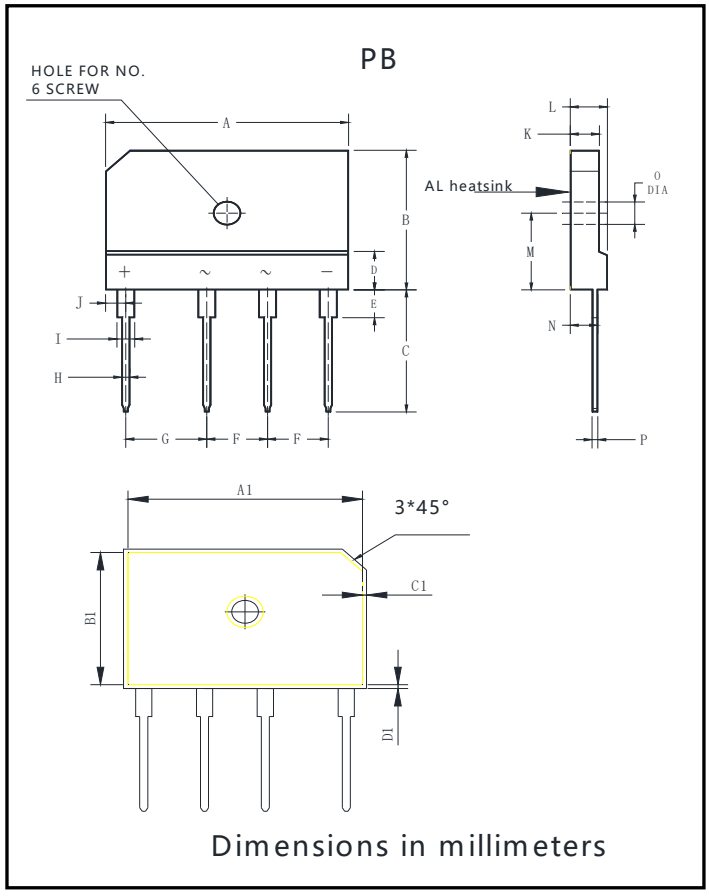
Electrical circuit diagram



Structural diagram



■ Outline Dimensions



PB		
Dim	**Min**	**Max**
A	29.7	30.3
B	19.7	20.3
C	17.0	18.0
D	4.8	5.8
E	3.8	4.2
F	7.3	7.7
G	9.8	10.2
H	0.9	1.1
I	2.0	2.4
J	2.3	2.7
K	3.4	3.8
L	4.4	4.8
M	10.8	11.2
N	3.1	3.7
O	3.1	3.4
P	0.6	0.8
A1	28.75	29.15
B1	18.75	19.15
C1	0.3	0.7
D1	0.3	0.7

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